NPN Silicon High-Voltage Power Transistor

This device is designed for use in line–operated equipment requiring high $f_{T\!\!\!\!T}$

Features

- High DC Current Gain
- High Current-Gain Bandwidth Product
- Low Output Capacitance
- These Devices are Pb-Free and are RoHS Compliant*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V _{CEO}	350	Vdc
Collector-Base Voltage	V _{CB}	450	Vdc
Emitter-Base Voltage	V_{EB}	5.0	Vdc
Collector Current – Continuous	Ι _C	0.3	Adc
Base Current	Ι _Β	150	mAdc
Total Power Dissipation @ T _C = 25°C Derate above 25°C	P _D	15 0.12	W mW/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

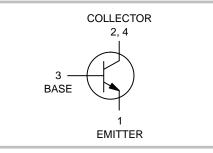
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	θ_{JC}	8.33	°C/W



ON Semiconductor®

http://onsemi.com

0.3 AMPERE POWER TRANSISTOR NPN SILICON 350 VOLTS, 15 WATTS





MARKING DIAGRAM



 Y
 = Year

 WW
 = Work Week

 E3439
 = Device Code

 G
 = Pb-Free Package

ORDERING INFORMATION

	evice	Package	Shipping
MJE	3439G	TO-225 (Pb-Free)	500 Units/Box

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MJE3439G

ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector–Emitter Sustaining Voltage $(I_{C} = 5.0 \text{ mAdc}, I_{B} = 0)$	V _{CEO(sus)}	350	-	Vdc
Collector Cutoff Current ($V_{CE} = 300 \text{ Vdc}, I_B = 0$)	I _{CEO}	_	20	μAdc
Collector Cutoff Current (V _{CE} = 450 Vdc, V _{EB(off)} = 1.5 Vdc)	ICEX	-	500	μAdc
Collector Cutoff Current ($V_{CB} = 350 \text{ Vdc}, I_E = 0$)	I _{CBO}	-	20	μAdc
Emitter Cutoff Current ($V_{BE} = 5.0 \text{ Vdc}, I_C = 0$)	I _{EBO}	_	20	μAdc
ON CHARACTERISTICS			•	
DC Current Gain ($I_C = 2.0 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}$) ($I_C = 20 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}$)	h _{FE}	30 15	200	-
Collector–Emitter Saturation Voltage $(I_C = 50 \text{ mAdc}, I_B = 4.0 \text{ mAdc})$	V _{CE(sat)}	-	0.5	Vdc
Base–Emitter Saturation Voltage (I _C = 50 mAdc, I _B = 4.0 mAdc)	V _{BE(sat)}	-	1.3	Vdc
Base–Emitter On Voltage (I _C = 50 mAdc, V _{CE} = 10 Vdc)	V _{BE(on)}	_	0.8	Vdc
DYNAMIC CHARACTERISTICS			•	
Current–Gain – Bandwidth Product ($I_C = 10 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}, f = 5.0 \text{ MHz}$)	f _T	15	-	MHz
Output Capacitance (V _{CB} = 10 Vdc, I _E = 0, f = 1.0 MHz)	C _{ob}	_	10	pF
Small–Signal Current Gain (I _C = 5.0 mAdc, V _{CE} = 10 Vdc, f = 1.0 kHz)	h _{fe}	25	_	-

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

MJE3439G

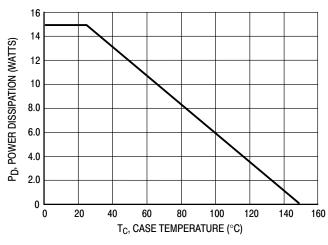


Figure 1. Power–Temperature Derating Curve

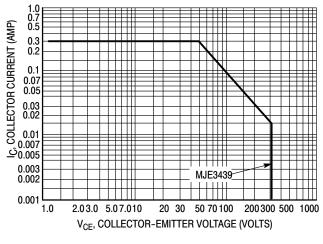
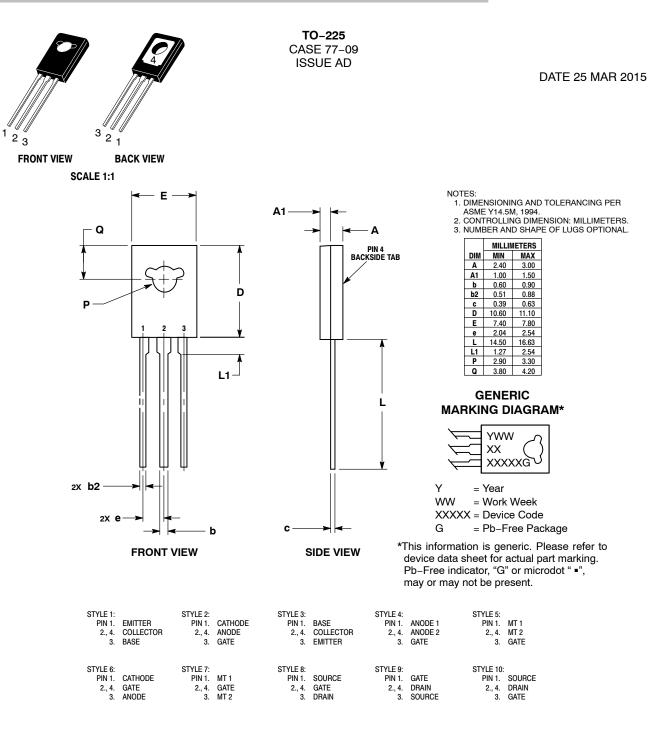


Figure 2. Active–Region Safe Operating Area

The Safe Operating Area Curves indicate $I_C - V_{CE}$ limits below which the device will not enter secondary breakdown. Collector load lines for specific circuits must fall within the applicable Safe Area to avoid causing a catastrophic failure. To insure operation below the maximum T_J , power–temperature derating must be observed for both steady state and pulse power conditions. MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

ON Semiconductor®





DOCUMENT NUMBER:	98ASB42049B	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.		
DESCRIPTION:	TO-225		PAGE 1 OF 1	
ON Semiconductor and 💷 are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries.				

ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

© Semiconductor Components Industries, LLC, 2019

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or indental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification. Buyer shall indemnify and hold onsemi and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs,

ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

Technical Library: www.onsemi.com/design/resources/technical-documentation onsemi Website: www.onsemi.com ONLINE SUPPORT: <u>www.onsemi.com/support</u> For additional information, please contact your local Sales Representative at www.onsemi.com/support/sales